



2.5V TO 3.3V HIGH PERFORMANCE CLOCK BUFFER

IDT5V2310

FEATURES:

- High performance 1:10 clock driver for general purpose applications
- Operates up to 200MHz at $V_{DD} = 3.3V$
- Pin-to-pin skew < 100ps
- V_{DD} range: 2.3V to 3.6V
- Output enable glitch suppression
- Distributes one clock input to two banks of five outputs
- 25 Ω on-chip series dampening resistors
- Available in TSSOP and VFQFPN packages

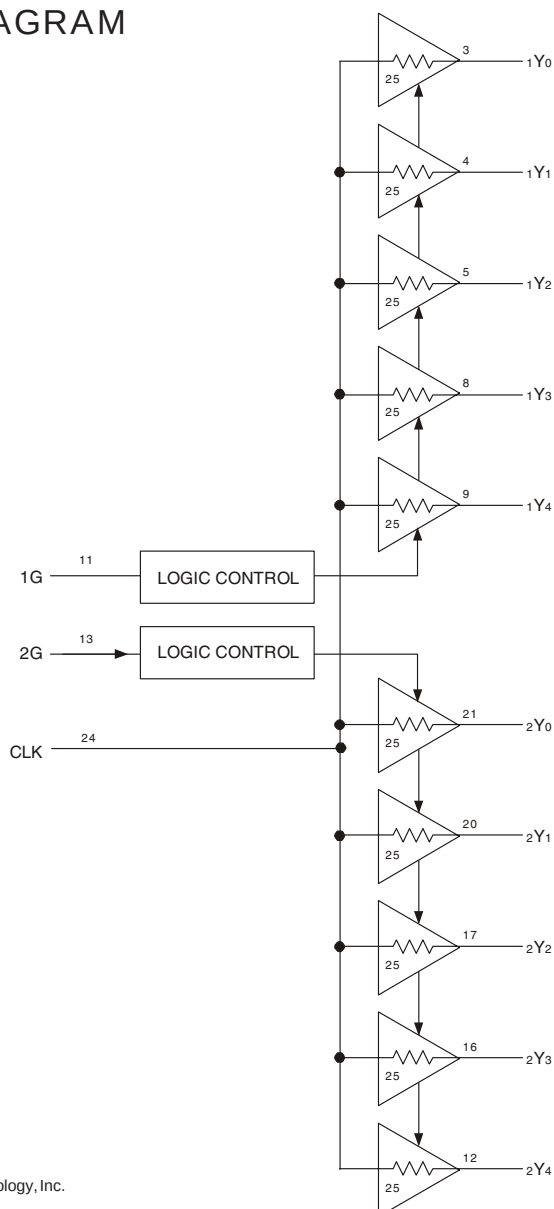
NOTE: EOL for non-green parts to occur on 5/13/10 per PDN U-09-01

DESCRIPTION:

The IDT5V2310 is a high performance, low skew clock buffer that operates up to 200MHz. Two banks of five outputs each provide low skew copies of CLK. Through the use of control pins 1G and 2G, the outputs of banks 1Y(0:4) and 2Y(0:4) can be placed in a low state regardless of CLK input. The device operates in 2.5V and 3.3V environments. The built-in output enable glitch suppression ensures a synchronized output enable sequence to distribute full period clock signals.

The IDT5V2310 is characterized for operation from -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM

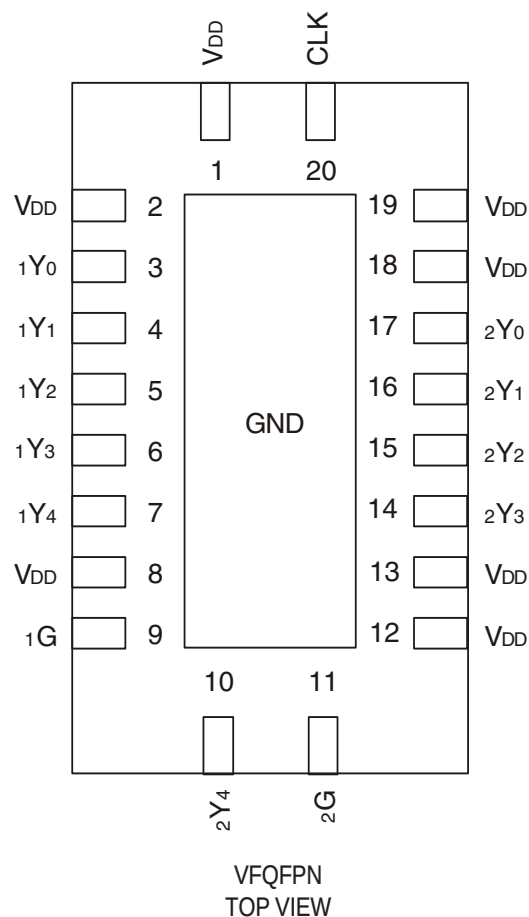
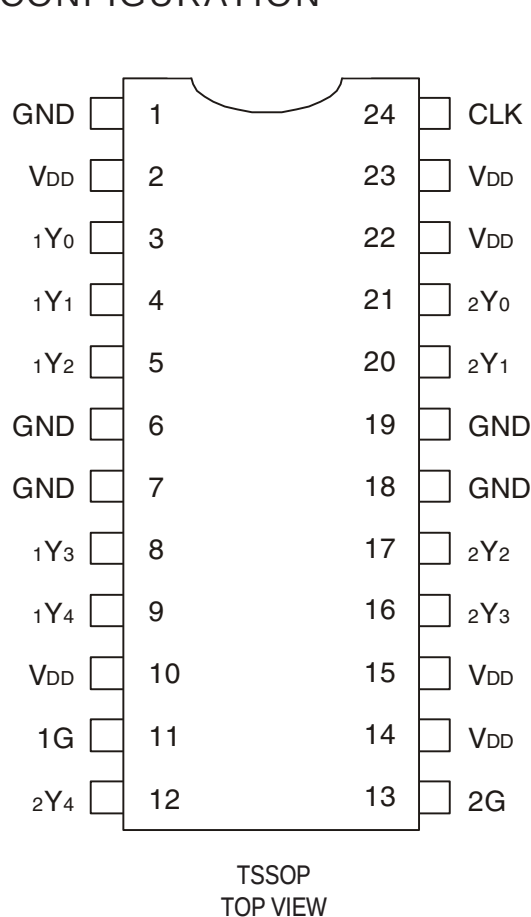


The IDT logo is a registered trademark of Integrated Device Technology, Inc.

INDUSTRIAL TEMPERATURE RANGE

NOVEMBER 2004

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
V _{DD}	Power Supply Voltage	-0.5 to +4.6	V
V _I	Input Voltage ⁽²⁾	-0.5 to V _{DD} +0.5	V
V _O	Output Voltage ⁽²⁾	-0.5 to V _{DD} +0.5	V
I _{IK}	Input Clamp Current V _I < 0 or V _I > V _{DD}	±50	mA
I _{OK}	Output Clamp Current V _O < 0 or V _O > V _{DD}	±50	mA
I _O	Continuous Total Output Current V _O < 0 to V _{DD}	±50	mA
T _{STG}	Storage Temperature	-65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- Not to exceed 4.6V.

CAPACITANCE (T_A = +25°C, f = 1MHz, V_{IN} = 0V)

Parameter	Description	Min.	Typ.	Max.	Unit
C _{IN}	Input Capacitance V _I = 0V or V _{DD}	—	2.5	—	pF

FUNCTION TABLE⁽¹⁾

Inputs			Outputs	
1G	2G	CLK	1Y(0:4)	2Y(0:4)
L	L	X	L	L
H	L	H	H	L
L	H	H	L	H
H	H	H	H	H

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care

PIN DESCRIPTION

TERMINAL		Description
Symbol	I/O	
1G	I	Output Enable Control for 1Y(0:4) Outputs. This output enable is active HIGH. If this pin is Logic HIGH, the 1Y(0:4) clock outputs will follow the input clock (CLK). If this pin is logic LOW, the 1Y(0:4) outputs will drive low independent of the state of CLK.
2G	I	Output Enable Control for 2Y(0:4) Outputs. This output enable is active HIGH. If this pin is Logic HIGH, the 2Y(0:4) clock outputs will follow the input clock (CLK). If this pin is logic LOW, the 2Y(0:4) outputs will drive low independent of the state of CLK.
1Y(0:4)	O	Buffered Output Clocks
2Y(0:4)	O	Buffered Output Clocks
CLK	I	Input Reference Frequency
GND		Ground
V _{DD}	PWR	DC Power Supply, 2.3V to 3.6V

RECOMMENDED OPERATING RANGE

Symbol	Description	Min.	Typ.	Max.	Unit
V _{DD}	Internal Power Supply Voltage	2.3	2.5		V
			3.3	3.6	
V _{IL}	Input Voltage LOW	V _{DD} = 3V to 3.6V		0.8	V
		V _{DD} = 2.3V to 2.7V		0.7	
V _{IH}	Input Voltage HIGH	V _{DD} = 3V to 3.6V		2	V
		V _{DD} = 2.3V to 2.7V		1.7	
V _I	Input Voltage	0		V _{DD}	V
I _{OH}	Output Current HIGH	V _{DD} = 3V to 3.6V		-12	mA
		V _{DD} = 2.3V to 2.7V		-6	
I _{OL}	Output Current LOW	V _{DD} = 3V to 3.6V		12	mA
		V _{DD} = 2.3V to 2.7V		6	
T _A	Ambient Operating Temperature	-40		+85	°C

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Unit
V _{IK}	Input Voltage	V _{DD} = 3V, I _{IN} = -18mA			-1.2	V
I _{IN}	Input Current	V _I = 0V or V _{DD}			±5	μA
I _{DD}	Static Device Current ⁽¹⁾	CLK = 0V or V _{DD} , I _O = 0mA, V _{DD} = 3.3V			25	μA

NOTE:

1. For I_{DD} over frequency, see TEST CIRCUIT AND WAVEFORMS.

DC ELECTRICAL CHARACTERISTICS - V_{DD} = 3.3V ± 0.3V

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max	Unit
V _{OH}	HIGH level Output Voltage	V _{DD} = Min. to Max.	I _{OH} = -100μA	V _{DD} - 0.2			V
		V _{DD} = 3V	I _{OH} = -12mA	2.1			
			I _{OH} = -6mA	2.4			
V _{OL}	LOW level Output Voltage	V _{DD} = Min. to Max.	I _{OL} = 100μA			0.2	V
		V _{DD} = 3V	I _{OL} = 12mA			0.8	
			I _{OL} = 6mA			0.55	
I _{OH}	HIGH level Output Current	V _{DD} = 3V	V _O = 1V	-28			mA
		V _{DD} = 3.3V	V _O = 1.65V		-36		
		V _{DD} = 3.6V	V _O = 3.135V			-14	
I _{OL}	LOW level Output Current	V _{DD} = 3V	V _O = 1.95V	28			mA
		V _{DD} = 3.3V	V _O = 1.65V		36		
		V _{DD} = 3.6V	V _O = 0.4V			14	

NOTE:

1. All typical values are at respective nominal V_{DD}.

DC ELECTRICAL CHARACTERISTICS - $V_{DD} = 2.5V \pm 0.2V$

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max	Unit
V_{OH}	HIGH level Output Voltage	$V_{DD} = \text{Min. to Max.}$	$I_{OH} = -100\mu A$	$V_{DD} - 0.2$			V
		$V_{DD} = 2.3V$	$I_{OH} = -6mA$	1.8			
V_{OL}	LOW level Output Voltage	$V_{DD} = \text{Min. to Max.}$	$I_{OL} = 100\mu A$			0.2	V
		$V_{DD} = 2.3V$	$I_{OL} = 6mA$			0.55	
I_{OH}	HIGH level Output Current	$V_{DD} = 2.3V$	$V_O = 1V$	-17			mA
		$V_{DD} = 2.5V$	$V_O = 1.25V$		-25		
		$V_{DD} = 2.7V$	$V_O = 2.375V$			-10	
I_{OL}	LOW level Output Current	$V_{DD} = 2.3V$	$V_O = 1.2V$	17			mA
		$V_{DD} = 2.5V$	$V_O = 1.25V$		25		
		$V_{DD} = 2.7V$	$V_O = 0.3V$			10	

NOTE:

1. All typical values are at respective nominal V_{DD} .

TIMING REQUIREMENTS OVER RECOMMENDED RANGE

Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Unit
f_{CLK}	Clock Frequency	$V_{DD} = 3V \text{ to } 3.6V$	0		200	MHz
		$V_{DD} = 2.3V \text{ to } 2.7V$	0		170	

SWITCHING CHARACTERISTICS OVER OPERATING RANGE -

$$V_{DD} = 3.3V \pm 0.3V^{(1)}$$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max	Unit
t _{PLH} t _{PHL}	CLK to Yx	f = 0MHz to 200MHz	1.3		2.8	ns
tsk(o) ⁽²⁾	Output Skew, Yx to Yx				100	ps
tsk(p)	Pulse Skew				250	ps
tsk(pp)	Part-to-Part Skew				500	ps
t _r	Rise Time	V _o = 0.4V to 2V ⁽³⁾	0.7		2	V/ns
t _f	Fall Time	V _o = 2V to 0.4V ⁽³⁾	0.7		2	V/ns
tsu	G before CLK↓	V _(THRESHOLD) = V _{DD} /2	0.1			ns
t _h	G after CLK↓		0.4			

NOTES:

1. All typical values are at respective nominal V_{DD}.
2. This specification is only valid for equal loading of all outputs.
3. Measured at 100MHz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE -

$$V_{DD} = 2.5V \pm 0.2V^{(1)}$$

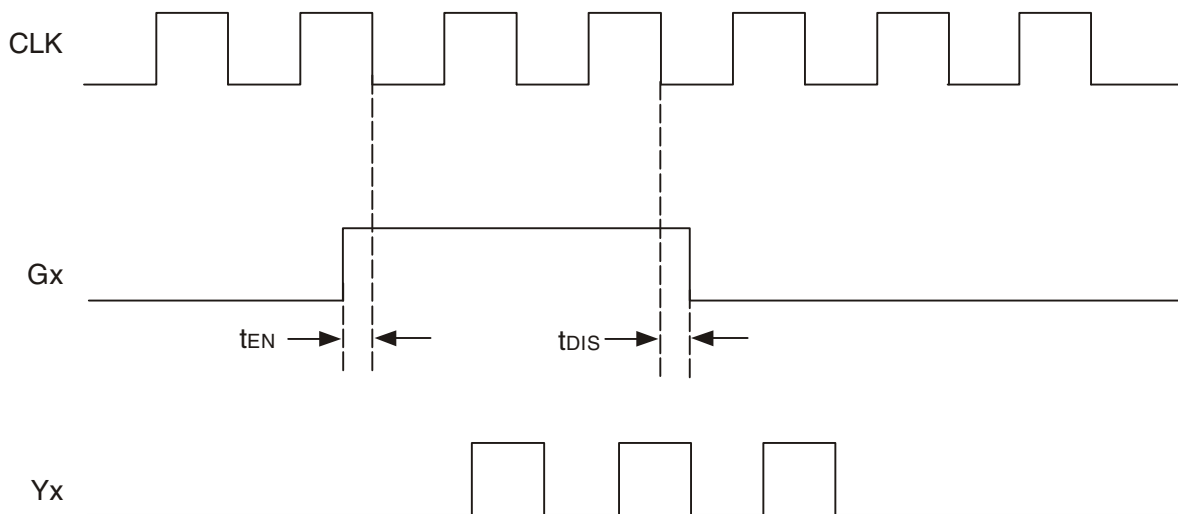
Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max	Unit
t _{PLH} t _{PHL}	CLK to Yx	f = 0MHz to 170MHz	1.5		3.5	ns
tsk(o) ⁽²⁾	Output Skew, Yx to Yx				100	ps
tsk(p)	Pulse Skew				400	ps
tsk(pp)	Part-to-Part Skew				600	ps
t _r	Rise Time	V _o = 0.4V to 1.7V ⁽³⁾	0.5		1.4	V/ns
t _f	Fall Time	V _o = 1.7V to 0.4V ⁽³⁾	0.5		1.4	V/ns
tsu	G before CLK↓	V _(THRESHOLD) = V _{DD} /2	0.1			ns
t _h	G after CLK↓		0.4			

NOTES:

1. All typical values are at respective nominal V_{DD}.
2. This specification is only valid for equal loading of all outputs.
3. Measured at 100MHz.

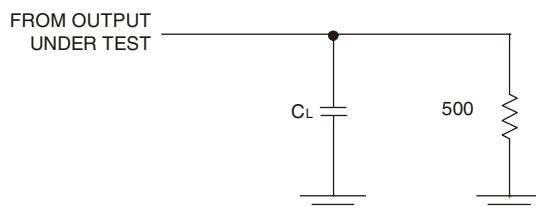
OUTPUT ENABLE GLITCH SUPPRESSION CIRCUIT

The purpose of the glitch suppression circuitry is to ensure the output enable sequence is synchronized with the clock input such that the output buffer will be enabled on the next full period of the input clock (negative edge triggered by the input clock). The G input must be stable one t_{EN} - time prior to the falling edge of the CLK for predictable operation.



$G(t_{EN}, t_{DIS})$ Relative to CLK↓

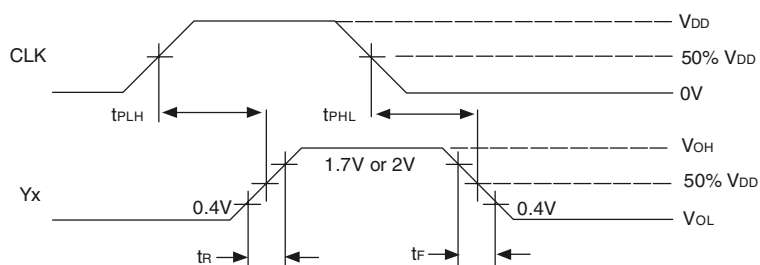
TEST CIRCUITS AND WAVEFORMS



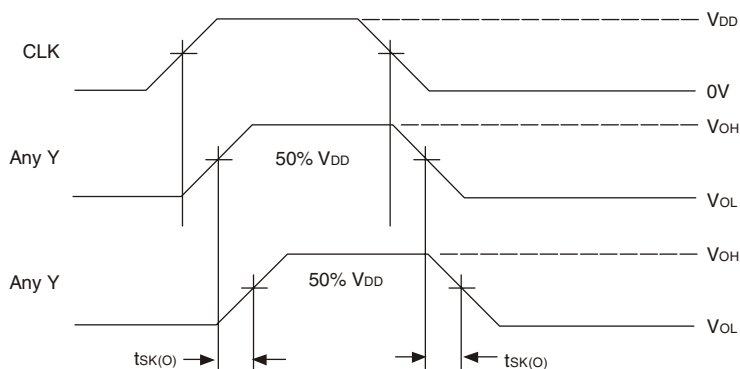
NOTES:

1. C_L includes probe and jig capacitance.
2. All input pulses are supplied by generators having the following characteristics:
 $PRR \leq 200\text{MHz}$; $Z_O = 50\Omega$; $t_R < 1.2\text{ns}$; $t_F < 1.2\text{ns}$.

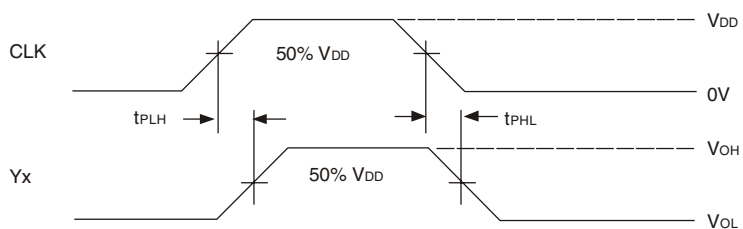
Test Load Circuit



Voltage Waveforms Propagation Delay Times



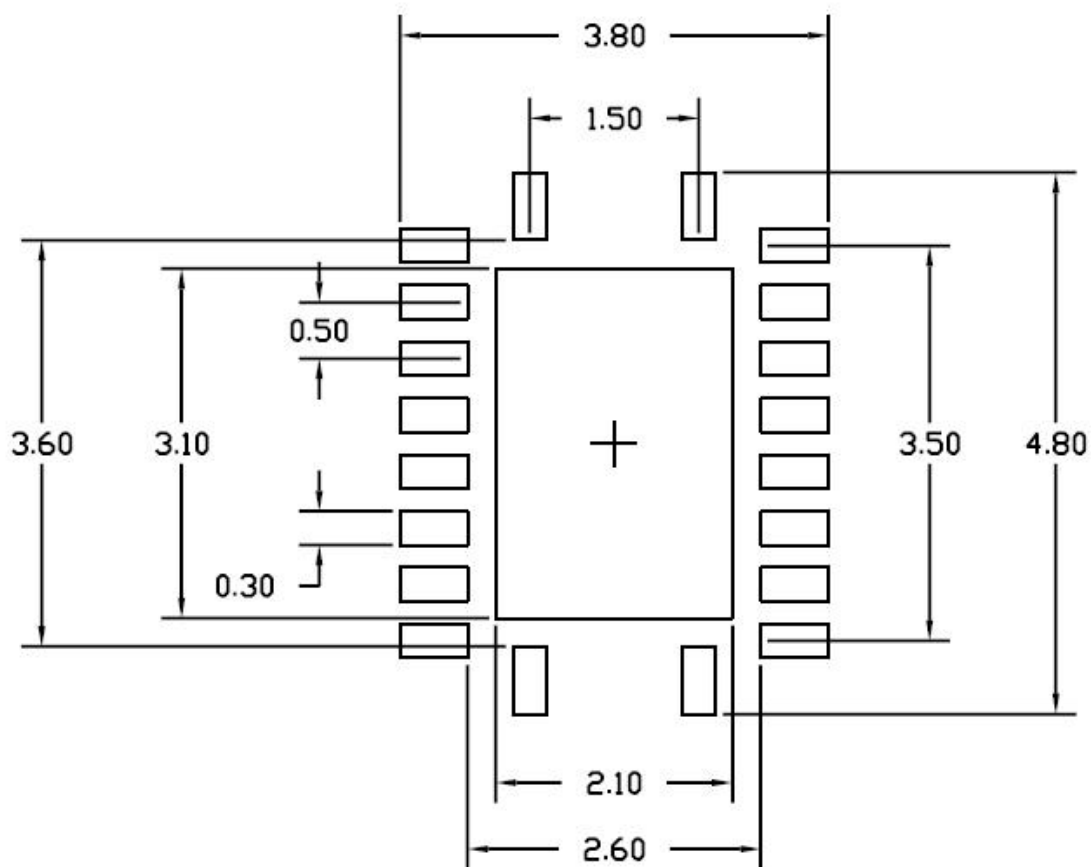
Output Skew



$$t_{SK(P)} = |t_{PLH} - t_{PHL}|$$

Pulse Skew

RECOMMENDED LANDING PATTERN

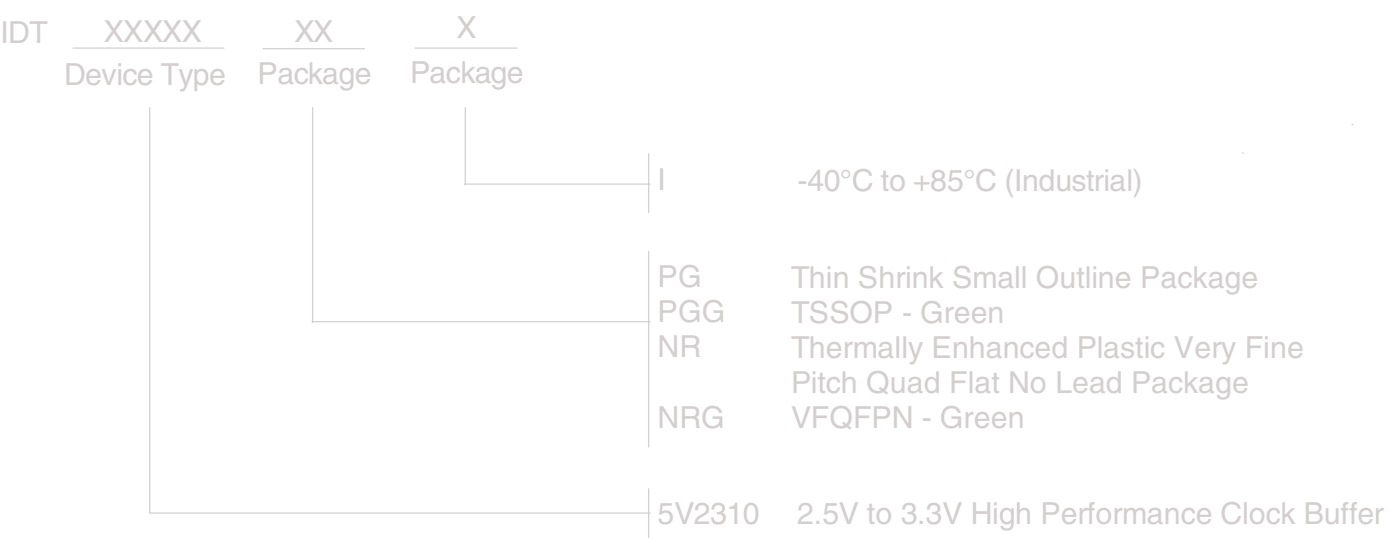


NR 20 pin

NOTE: All dimensions are in millimeters.

ORDERING INFORMATION

NOTE: EOL for non-green parts to occur on 5/13/10 per PDN U-09-01



CORPORATE HEADQUARTERS
6024 Silver Creek Valley Road
San Jose, CA 95138

for SALES:
800-345-7015 or 408-284-8200
fax: 408-284-2775
www.idt.com

for Tech Support:
clockhelp@idt.com

IDT	XXXXX	XX	X		
	Device Type	Package	Package		
				I	-40°C to +85°C (Industrial)
				PG	Thin Shrink Small Outline Package
				PGG	TSSOP - Green
				NR	Thermally Enhanced Plastic Very Fine Pitch Quad Flat No Lead Package
				NRG	VFQFPN - Green
				5V2310	2.5V to 3.3V High Performance Clock Buffer